

100343 Low Power 8-Bit Latch

General Description

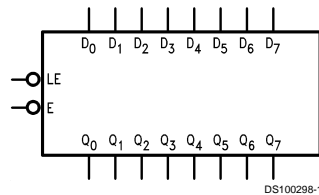
The 100343 contains eight D-type latches, individual inputs, (D_n), outputs (Q_n), a common enable pin (\bar{E}), and a latch enable pin (\overline{LE}). A Q output follows its D input when both \bar{E} and \overline{LE} are LOW. When either \bar{E} or \overline{LE} are HIGH, a latch stores the last valid data present on its D input prior to \bar{E} or \overline{LE} going HIGH.

The 100343 outputs are designed to drive a 50 Ω termination resistor to -2.0V. All inputs have 50 k Ω pull-down resistors.

Features

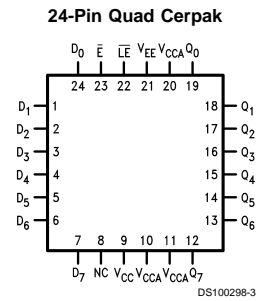
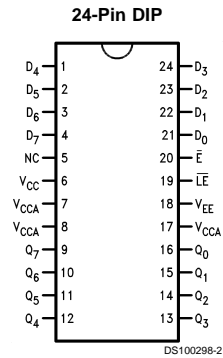
- Low power operation
- 2000V ESD protection
- Voltage compensated operating range = -4.2V to -5.7V
- Available to MIL-STD-883

Logic Symbol

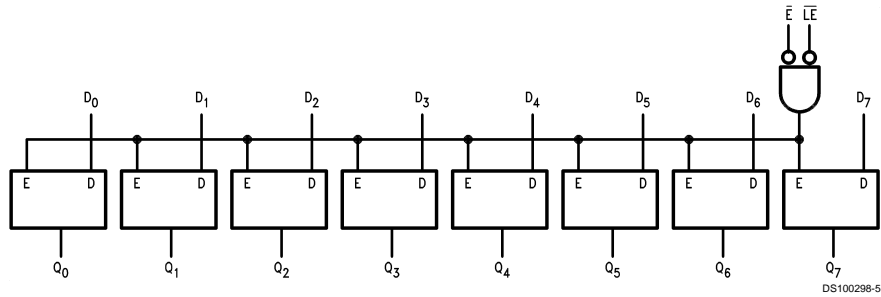


Pin Names	Description
D_0 - D_7	Data Inputs
\bar{E}	Enable Input
\overline{LE}	Latch Enable Input
Q_0 - Q_7	Data Outputs
NC	No Connect

Connection Diagrams



Logic Diagram



Truth Table

Inputs			Outputs
D_n	\bar{E}	\bar{LE}	Q_n
L	L	L	L
H	L	L	H
X	H	X	Latched (Note 1)
X	X	H	Latched (Note 1)

H = HIGH voltage level
L = LOW voltage level
X = Don't care

Note 1: Retains data present before either \bar{LE} or \bar{E} went HIGH

Absolute Maximum Ratings (Note 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Storage Temperature (T _{STG})	-65°C to +150°C
Maximum Junction Temperature (T _J)	
Ceramic	+175°C
V _{EE} Pin Potential to Ground Pin	-7.0V to +0.5V
Input Voltage (DC)	V _{EE} to +0.5V
Output Current (DC Output HIGH)	-50 mA
ESD (Note 3)	≥2000V

Recommended Operating Conditions

Case Temperature (T _C)	
Military	-55°C to +125°C
Supply Voltage (V _{EE})	-5.7V to -4.2V

Note 2: Absolute maximum ratings are those values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: ESD testing conforms to MIL-STD-883, Method 3015.

Military Version DC Electrical Characteristics

V_{EE} = -4.2V to -5.7V, V_{CC} = V_{CCA} = GND, T_C = -55°C to +125°C

Symbol	Parameter	Min	Max	Units	T _C	Conditions	Notes	
V _{OH}	Output HIGH Voltage	-1025	-870	mV	0°C to +125°C	V _{IN} = V _{IH} (Max) or V _{IL} (Min)	Loading with 50Ω to -2.0V	1, 2, 3
		-1085	-870	mV	-55°C			
V _{OL}	Output LOW Voltage	-1830	-1620	mV	0°C to +125°C	V _{IN} = V _{IH} (Max) or V _{IL} (Min)	Loading with 50Ω to -2.0V	1, 2, 3
		-1830	-1555	mV	-55°C			
V _{OHC}	Output HIGH Voltage	-1035		mV	0°C to +125°C	V _{IN} = V _{IH} (Max) or V _{IL} (Min)	Loading with 50Ω to -2.0V	1, 2, 3
		-1085		mV	-55°C			
V _{OLC}	Output LOW Voltage		-1610	mV	0°C to +125°C	V _{IN} = V _{IH} (Max) or V _{IL} (Min)	Loading with 50Ω to -2.0V	1, 2, 3
			-1555	mV	-55°C			
V _{IH}	Input HIGH Voltage	-1165	-870	mV	-55°C to +125°C	Guaranteed HIGH Signal for All Inputs	1, 2, 3, 4	
V _{IL}	Input LOW Voltage	-1830	-1475	mV	-55°C to +125°C	Guaranteed LOW Signal for All Inputs	1, 2, 3, 4	
I _{IL}	Input LOW Current	0.50		μA	-55°C to +125°C	V _{EE} = -4.2V V _{IN} = V _{IL} (Min)	1, 2, 3	
I _{IH}	Input HIGH Current		240	μA	0°C to +125°C	V _{EE} = -5.7V V _{IN} = V _{IH} (Max)	1, 2, 3	
			340	μA	-55°C			
I _{EE}	Power Supply Current	-100 -105	-35 -35	mA	-55°C to +125°C	Inputs Open V _{EE} = -4.2V to -4.8V V _{EE} = -4.2V to -5.7V	1, 2, 3	

Note 4: F100K 300 Series cold temperature testing is performed by temperature soaking (to guarantee junction temperature equals -55°C), then testing immediately without allowing for the junction temperature to stabilize due to heat dissipation after power-up. This provides "cold start" specs which can be considered a worst case condition at cold temperatures.

Note 5: Screen tested 100% on each device at -55°C, +25°C, and +125°C, Subgroups 1, 2, 3, 7, and 8.

Note 6: Sample tested (Method 5005, Table I) on each manufactured lot at -55°C, +25°C, and +125°C, Subgroups A1, 2, 3, 7, and 8.

Note 7: Guaranteed by applying specified input condition and testing V_{OH}/V_{OL}.

Military Version AC Electrical Characteristics

V_{EE} = -4.2V to -5.7V, V_{CC} = V_{CCA} = GND

Symbol	Parameter	T _C = -55°C		T _C = +25°C		T _C = +125°C		Units	Conditions	Notes
		Min	Max	Min	Max	Min	Max			
t _{PLH}	Propagation Delay	0.50	2.70	0.50	2.30	0.50	2.80	ns	Figures 1, 2, 3	(Notes 8, 9, 10, 12)
t _{PHL}	D _n to Output									

Military Version AC Electrical Characteristics (Continued)

$V_{EE} = -4.2V$ to $-5.7V$, $V_{CC} = V_{CCA} = GND$

Symbol	Parameter	$T_C = -55^\circ C$		$T_C = +25^\circ C$		$T_C = +125^\circ C$		Units	Conditions	Notes
		Min	Max	Min	Max	Min	Max			
t_{PLH} t_{PHL}	Propagation Delay \overline{LE} , \overline{E} to Output	0.90	3.40	1.0	3.10	1.10	3.90	ns	Figures 1, 2, 3	(Notes 8, 9, 10, 12)
t_{TLH} t_{THL}	Transition Time 20% to 80%, 80% to 20%	0.40	2.50	0.40	2.40	0.40	2.70	ns	Figures 1, 3	(Note 11)
t_s	Setup Time D_0-D_7	0.60		0.60		0.60		ns	Figures 1, 4	(Note 11)
t_h	Hold Time D_0-D_7	1.50		1.50		1.70		ns	Figures 1, 4	(Note 11)
$t_{pw(H)}$	Pulse Width HIGH \overline{LE} , \overline{E}	2.40		2.40		2.40		ns	Figures 1, 4	(Note 11)

Note 8: F100K 300 Series cold temperature testing is performed by temperature soaking (to guarantee junction temperature equals $-55^\circ C$), then testing immediately after power-up. This provides "cold start" specs which can be considered a worst case condition at cold temperatures.

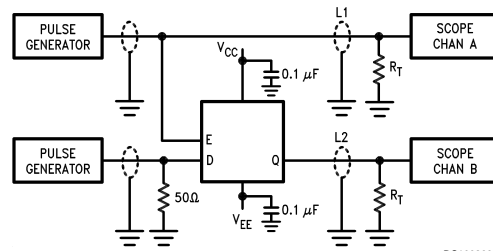
Note 9: Screen tested 100% on each device at $+25^\circ C$ temperature only, Subgroup A9.

Note 10: Sample tested (Method 5005, Table I) on each manufactured lot at $+25^\circ C$, Subgroup A9, and at $+125^\circ C$ and $-55^\circ C$ temperatures, Subgroups A10 and A11.

Note 11: Not tested at $+25^\circ C$, $+125^\circ C$, and $-55^\circ C$ temperature (design characterization data).

Note 12: The propagation delay specified is for single output switching. Delays may vary up to 300 ps with multiple outputs switching.

Test Circuitry



DS100298-6

Note 13: V_{CC} , $V_{CCA} = +2V$, $V_{EE} = -2.5V$

Note 14: L1 and L2 = equal length 50Ω impedance lines

$R_T = 50\Omega$ terminator internal to scope

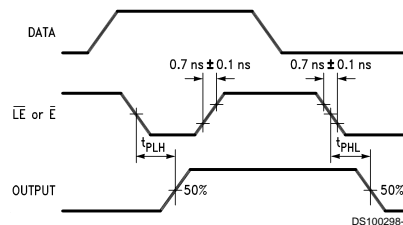
Decoupling 0.1 μF from GND to V_{CC} and V_{EE}

All unused outputs are loaded with 50Ω to GND

C_L = Fixture and stray capacitance ≤ 3 pF

FIGURE 1. AC Test Circuit

Switching Waveforms



DS100298-7

FIGURE 2. Propagation Delays

Switching Waveforms (Continued)

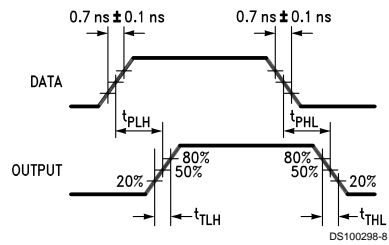


FIGURE 3. Propagation and Transition Times

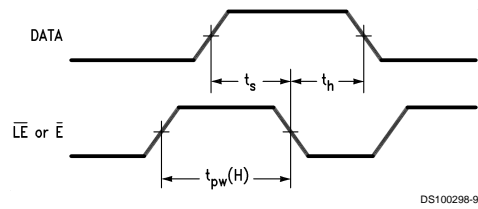
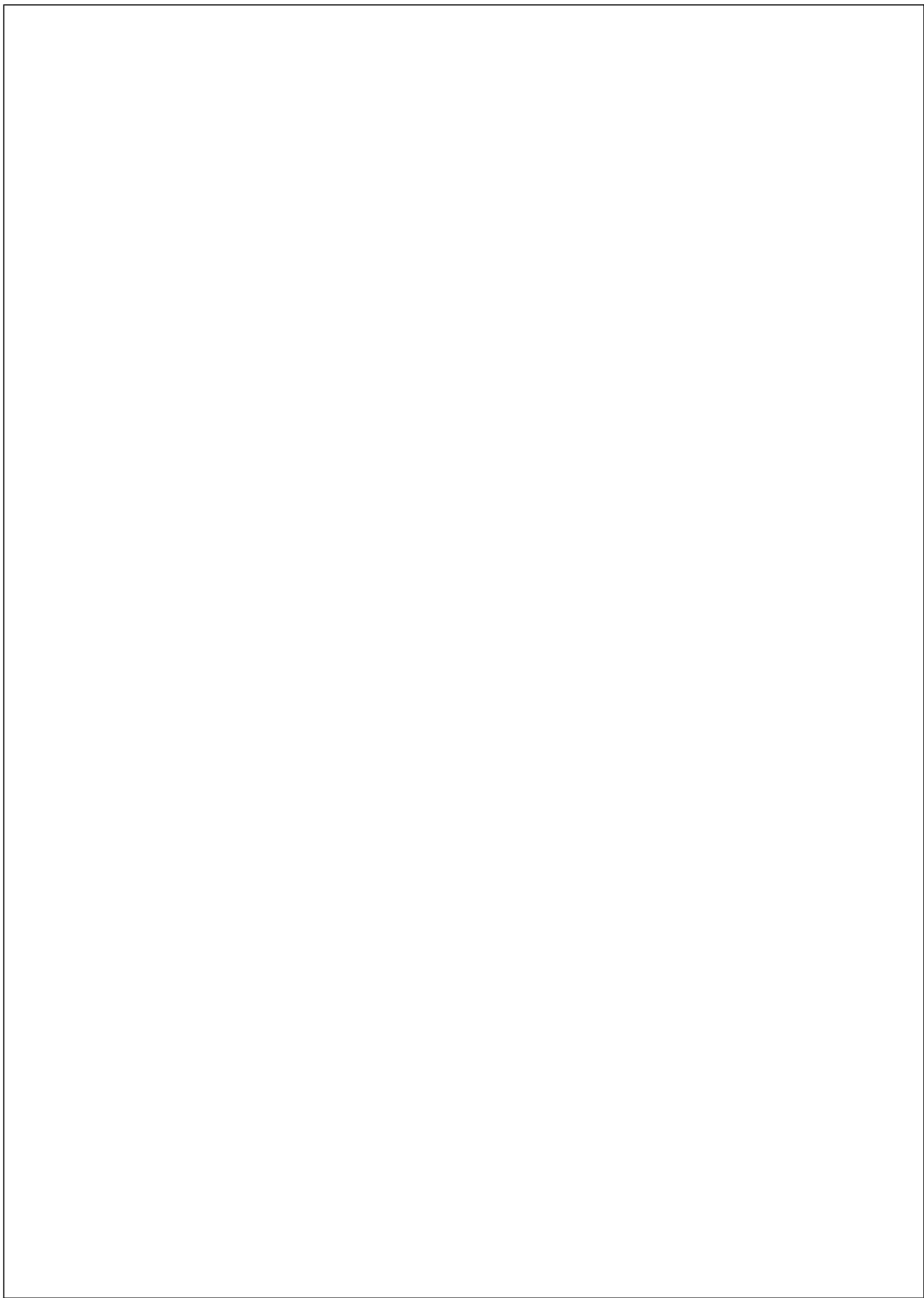
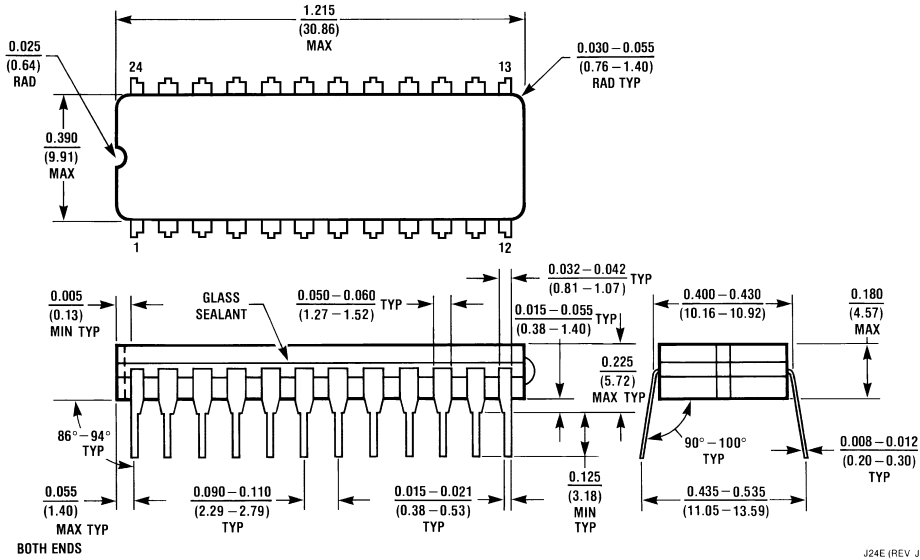


FIGURE 4. Setup, Hold and Pulse Width Times

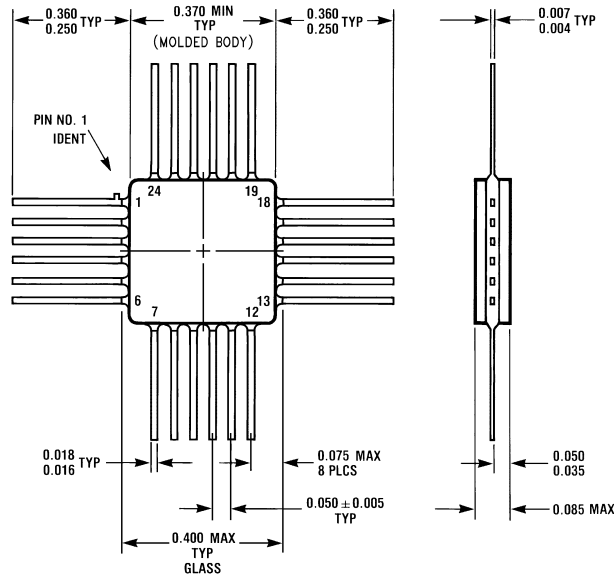


Physical Dimensions inches (millimeters) unless otherwise noted



24-Pin Ceramic Dual-In-Line Package (D)
NS Package Number J24E

J24E (REV J)



24-Lead Quad Cerpak (F)
NS Package Number W24B

W24B (REV D)

LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



National Semiconductor Corporation
Americas
Tel: 1-800-272-9959
Fax: 1-800-737-7018
Email: support@nsc.com

www.national.com

National Semiconductor Europe
Fax: +49 (0) 1 80-530 85 86
Email: europe.support@nsc.com
Deutsch Tel: +49 (0) 1 80-530 85 85
English Tel: +49 (0) 1 80-532 78 32
Français Tel: +49 (0) 1 80-532 93 58
Italiano Tel: +49 (0) 1 80-534 16 80

National Semiconductor Asia Pacific Customer Response Group
Tel: 65-2544466
Fax: 65-2504466
Email: sea.support@nsc.com

National Semiconductor Japan Ltd.
Tel: 81-3-5620-6175
Fax: 81-3-5620-6179